Gates Institute of Technology
Affiliated to JNTUA, Ananthapuramu and Approved by AICTE, New Delhi
Accredited by NAAC
NH 44, GOOTY, Ananthapuramu Dist. 515401

FACULTY PROFILE



1. Name : Dr. D. Jhansi Rani
2. Designation : Associate Professor
3. Date of Birth : 03-06-1988
4. Department : H & BS
5. Highest Qualification : M. Sc, PhD
6. Academic Performance :

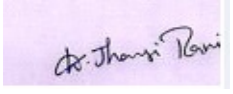
S. No	Degree	University/ Institution	Year of Pass	Specialization	Class
1	PhD	Sri Krishnadevaraya University, Anantapuramu	2017	Thin films	
2	M. Sc.,	Sri Krishnadevaraya University, Anantapuramu	2011	Electronics	Distinction

7. Total Years of teaching /industry experience till date : 07
8. Date of joining in this Department : 07-02-2024
9. Designation as on date of joining : Associate Professor
10. Achievements :

S. No.	Achievemens	
1	Number of papers published	13
2	Number of papers presented in conferences	04
3	Number of Projects guided	00
4	Number of FDPs /STTPs/Workshop Attended	09/00/04
5	Number of National/ International Conferences Attended	08
6	Others (Book Chapters/Patents etc)	0

11. Area of Interests:

Nano Materials, High-k Dielectric Materials, Transparent Conducting Oxides, Thin Films, Ceramics.



Signature of the faculty